

HD74BC541A

Octal Buffers/Line Drivers With 3 State Outputs

REJ03D0286-0200Z
(Previous ADE-205-023 (Z))
Rev.2.00
Jul.16.2004

Description

The HD74BC541A provides high drivability and operation equal to or better than high speed bipolar standard logic IC by using Bi-CMOS process. The device features low power dissipation that is about 1/5 of high speed bipolar logic IC, when the frequency is 10 MHz. The device has eight inverter drivers with three state outputs in a 20 pin package. When $\bar{G}1$ and $\bar{G}2$ is low level, this drivers set up output is enable.

Features

- Input/Output are at high impedance state when power supply is off.
- Built in input pull up circuit can make input pins be open, when not used.
- Input is TTL level.
- Wide operating temperature range
 $T_a = -40$ to $+85^{\circ}\text{C}$
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74BC541AFPEL	SOP-20 pin (JEITA)	FP-20DAV	FP	EL (2,000 pcs/reel)

Function Table

Inputs			Output Y
$\bar{G}1$	$\bar{G}2$	A	
L	L	L	L
L	L	H	H
H	X	X	Z
X	H	X	Z

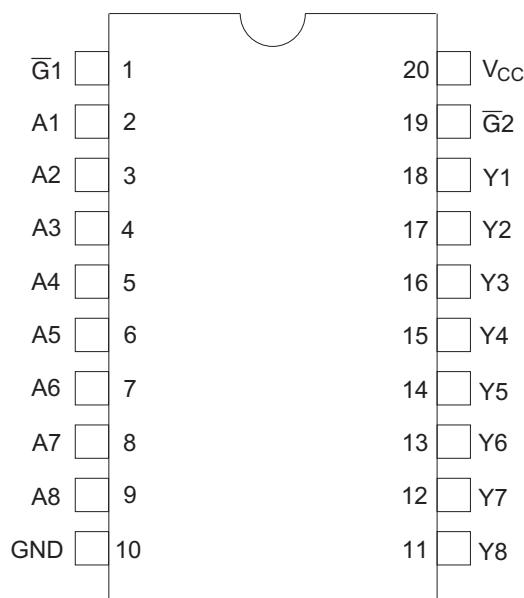
H : High level

L : Low level

X : Immaterial

Z : High impedance

Pin Arrangement



(Top view)

Absolute Maximum Ratings

Item	Symbol	Rating	Unit
Supply voltage	V _{CC}	-0.5 to +7.0	V
Input diode current	I _{IK}	±30	mA
Input voltage	V _{IN}	-0.5 to +7.5	V
Output voltage	V _{OUT}	-0.5 to +7.5	V
Off state output voltage	V _{OUT(off)}	-0.5 to +5.5	V
Storage temperature	T _{STG}	-65 to +150	°C

Note: 1. The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

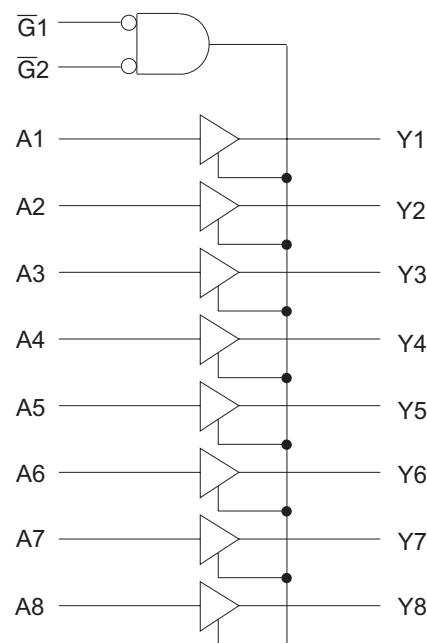
Recommended Operating Conditions

Item	Symbol	Min	Typ	Max	Unit
Supply voltage	V _{CC}	4.5	5.0	5.5	V
Input voltage	V _{IN}	0	—	V _{CC}	V
Output voltage	V _{OUT}	0	—	V _{CC}	V
Operating temperature	T _{OPR}	-40	—	85	°C
Input rise/fall time* ¹	t _r , t _f	0	—	8	ns/V

Note: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

Logic Diagram



Electrical Characteristics ($T_a = -40$ to $+85^\circ\text{C}$)

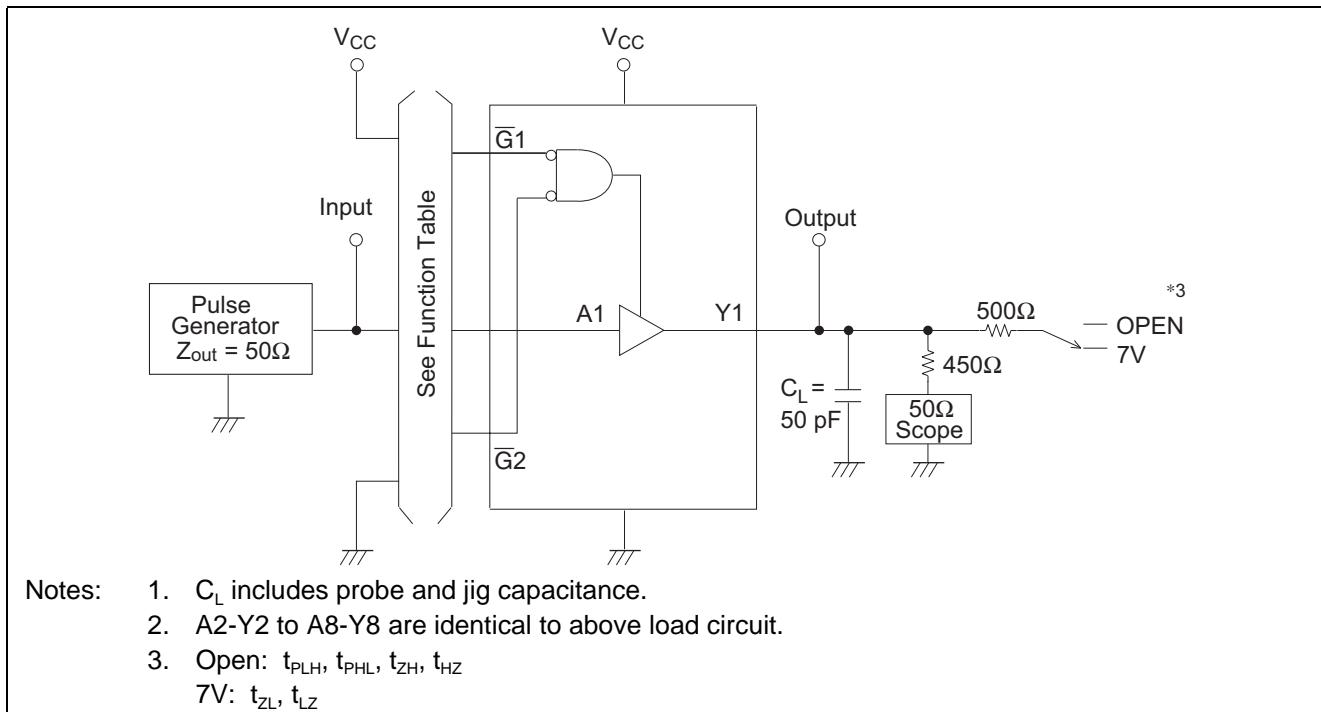
Item	Symbol	$V_{cc}(\text{V})$	Min	Max	Unit	Test Conditions
Input voltage	V_{IH}		2.0	—	V	
	V_{IL}		—	0.8	V	
Output voltage	V_{OH}	4.5	2.4	—	V	$I_{OH} = -3 \text{ mA}$
		4.5	2.0	—	V	$I_{OH} = -15 \text{ mA}$
	V_{OL}	4.5	—	0.5	V	$I_{OL} = 48 \text{ mA}$
		4.5	—	0.55	V	$I_{OL} = 64 \text{ mA}$
Input diode voltage	V_{IK}	4.5	—	-1.2	V	$I_{IN} = -18 \text{ mA}$
Input current	I_I	5.5	—	-250	μA	$V_{IN} = 0 \text{ V}$
		5.5	—	1.0	μA	$V_{IN} = 5.5 \text{ V}$
		5.5	—	100	μA	$V_{IN} = 7.0 \text{ V}$
Short circuit output current* ¹	I_{OS}	5.5	-100	-225	mA	$V_{IN} = 0$ or 5.5 V
Off state output current	I_{OZH}	5.5	—	50	μA	$V_O = 2.7 \text{ V}$
	I_{OZL}	5.5	—	-50	μA	$V_O = 0.5 \text{ V}$
Supply current	I_{CCL}	5.5	—	29.5	mA	$V_{IN} = V_{CC}$ or GND All outputs is "L"
	I_{CCH}	5.5	—	0.5	mA	$V_{IN} = V_{CC}$ or GND All outputs is "H"
	I_{CCZ}	5.5	—	2.5	mA	$V_{IN} = V_{CC}$ or GND All outputs is "Z"
	I_{CCT}^{*2}	5.5	—	1.5	mA	$V_{IN} = 3.4\text{V}$ or 0.5V

Notes: 1. Not more than one output should be shorted at a time and duration of the short circuit should not exceed one second.
 2. When input by the TTL level, it shows I_{CC} increase at per one input pin.

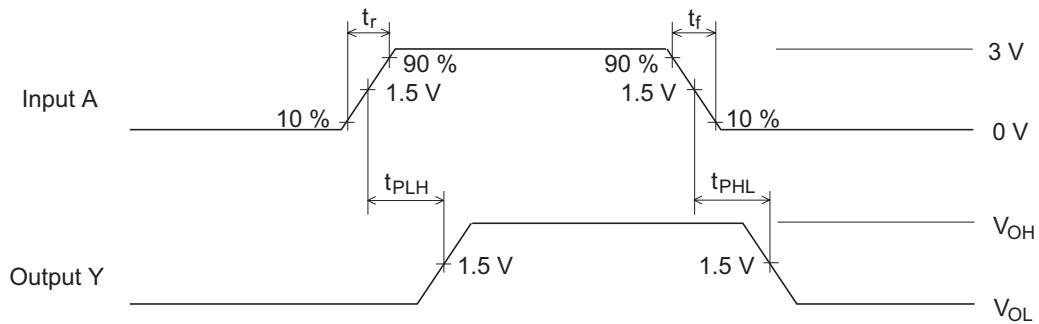
Switching Characteristics ($C_L = 50 \text{ pF}$)

Item	Symbol	$T_a = 25^\circ\text{C}$ $V_{cc} = 5.0 \text{ V}$		$T_a = -40$ to $+85^\circ\text{C}$ $V_{cc} = 5.0 \text{ V} \pm 10\%$		Unit	Test Conditions
		Min	Max	Min	Max		
Propagation delay time	t_{PLH}	3.0	6.0	3.0	7.0	ns	See under figure
	t_{PHL}	3.0	6.0	3.0	7.0		
Output enable time	t_{ZH}	3.0	9.0	3.0	11.0	ns	
	t_{ZL}	3.0	9.0	3.0	11.0		
Output disable time	t_{HZ}	3.0	8.0	3.0	10.0	ns	
	t_{LZ}	3.0	8.0	3.0	10.0		
Input capacitance	C_{IN}	3.0 (Typ)		—		pF	$V_{IN} = V_{CC}$ or GND
Output capacitance	C_O	15.0 (Typ)		—		pF	$V_O = V_{CC}$ or GND

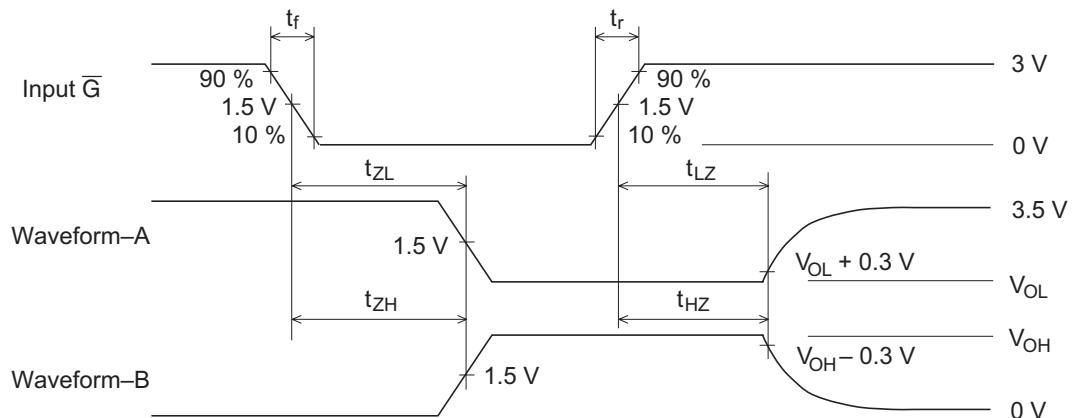
Test circuit



Waveforms-1



Waveforms-2



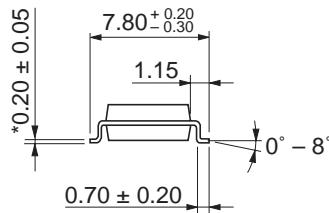
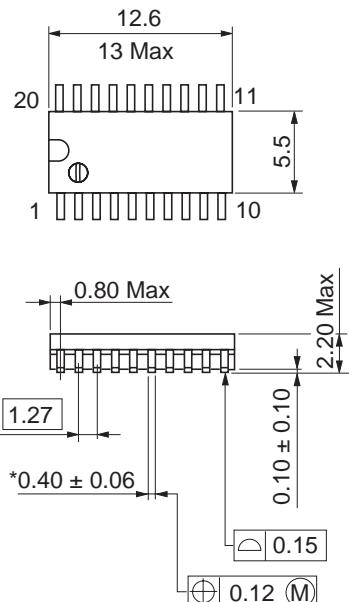
Notes:

1. $t_r = 2.5$ ns, $t_f = 2.5$ ns
2. Input waveforms: PRR = 1 MHz, duty cycle 50%
3. Waveform-A shows input conditions such that the output is "L" level when enable by the output control.
4. Waveform-B shows input conditions such that the output is "H" level when enable by the output control.

Package Dimensions

As of January, 2003

Unit: mm



*Ni/Pd/Au plating

Package Code	FP-20DAV
JEDEC	—
JEITA	Conforms
Mass (reference value)	0.31 g

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